

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

Attorney Docket Number	23-65037
Application Number	10/726,744
Filing Date	December 2, 2003
First Named Inventor	Larry C. Olsen
Art Unit	1753
Examiner Name	Not yet assigned

U.S. PATENT DOCUMENTS

NOTE: If this application was filed after June 30, 2003, copies of United States patents and United States published patent applications do not have to be provided to the Patent Office. This requirement of 37 C.F.R. § 1.98(a)(2)(i) has been waived by the United States Patent and Trademark Office pursuant to the Official Gazette Notice on August 5, 2003 (1276 OG 55).

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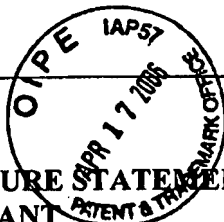
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